



Sheet 1 of 1

ATTY. DOCKET NO. APPLICATION NO. U.S. DEPARTMENT OF COMMERCE FORM PTO-1449 PATENT AND TRADEMARK OFFICE 501082.03 (98-0616.02) 09/652,841 (REV.7-80) APPLICANT(S) NHORMATION DISCLOSURE STATEMENT Vishnu K. Agarwal (se several sheets if necessary) GROUP ART UNIT FILING DATE August 31, 2000 2815 U.S. PATENT DOCUMENTS CLASS SUBCLASS FILING DATE DOCUMENT NUMBER DATE NAME IF APPROPRIATE 190 5,552,339 09/03/96 437 Hsieh AA 438 627 6:136,690 10/24/00 Li ΑB AC AD 7 7 FOREIGN PATENT DOCUMENTS **SUBCLASS** TRANSLATION DATE COUNTRY CLASS DOCUMENT NUMBER X 01/26/80 JP (Abstract only) 355011329 A ΑE X 03/10/98 410070091 A JP (Abstract only) ΑF OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.) Anonymous, "Oxide-Free Dielectric/GaAs Interface With No Excess As", IBM Technical Disclosure Bulletin, Vol. 33, No. 11, April 1, 1991, p. 352. AG Schúlz, S.E. et al., "Influence of Water Preclean Before Selective Tungsten CVD on Surface Properties of Interconnect and Intermetal Dielectric Materials", Physica Status Solidi A Vol. 145, No. 2, October 16, 1994, pp. 311-318. DATE CONSIDERED Initial if reference considered, whether or not criteria is in conformance with MPEP 609. Draw line through citation if not in * EXAMINER: conformance and not considered. Include copy of this form with next communication to applican(s).